



4-Bit Bidirectional Voltage-Level Translator for Open-Drain and Push-Pull Applications

FEATURES

- No Direction-Control
- Data Rates
 24Mbps (Push-Pull)
 2Mbps (Open-Drain)
- 1.65V to 5.5V on A ports and 2.3V to 5.5V on B Ports (V_{CCA}≤V_{CCB})
- V_{CC} Isolation: If Either V_{CC} is at GND, Both Ports are in the High-Impedance State
- No Power-Supply Sequencing Required: Either V_{CCA} or V_{CCB} can be Ramped First
- I_{OFF}: Supports Partial-Power-Down Mode Operation
- Extended Temperature: -40°C to +85°C

APPLICATIONS

- Handset
- Smartphone
- Tablet
- Desktop PC

DESCRIPTION

This 4-bit non-inverting translator is a bidirectional voltage-level translator and can be used to establish digital switching compatibility between mixed-voltage systems. It uses two separate configurable power-supply rails, with the A ports supporting operating voltages from 1.65V to 5.5V while it tracks the $V_{\rm CCA}$ supply, and the B ports supporting operating voltages from 2.3V to 5.5V while it tracks the $V_{\rm CCB}$ supply. This allows the support of both lower and higher logic signal levels while providing bidirectional translation capabilities between any of the 1.8V, 2.5V, 3.3V and 5V voltage nodes.

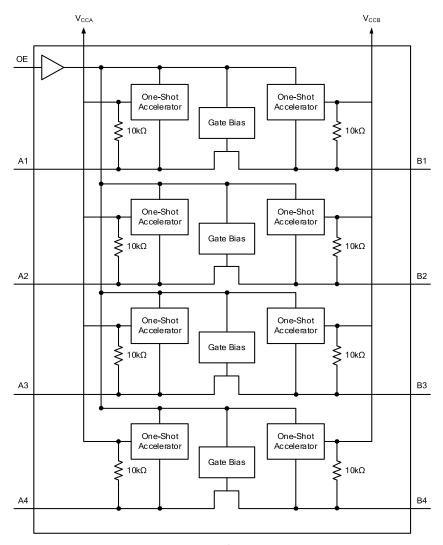
When the output-enable (OE) input is low, all I/Os are placed in the high-impedance state, which significantly reduces the power-supply quiescent current consumption. OE has an internal pull-down current source, as long as V_{CCA} is powered.

To ensure the high-impedance state during power up or power down, OE should be tied to GND through a pull-down resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

The RS0104 is available in Green QFN3.5x3.5-14L, QFN2x2-12L, QFN2x1.7-12L and TSSOP-14 packages. It operates over an ambient temperature range of -40°C to +85°C.



Functional Block Diagram



Block Diagram

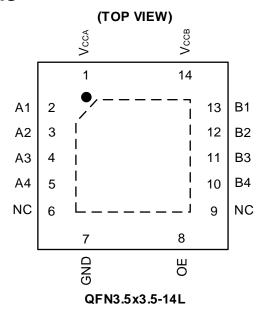


Revision History

Note: Page numbers for previous revisions may different from page numbers in the current version.

VERSION	Change Date	Change Item
A.1	2020/11/03	Initial version completed
A.2	2021/01/09	Add Moisture Sensitivity Level information
A.3	2021/04/02	Add QFN2x1.7-12L package
A.4	2021/10/12	1.Change QFN3.5x3.5-14L PACKAGE OPTION 2.Add TAPE AND REEL INFORMATION
A.5	2021/11/01	Change Recommended Operating Conditions in Page 9 @A.4 Version. Add Typical Characteristics

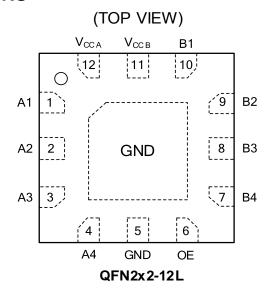




PIN		T)/DE (1)	FUNCTION		
QFN3.5x3.5-14L	NAME	TYPE (1)	FUNCTION		
1	Vcca	Р	A Port Supply Voltage.1.65V ≤ V _{CCA} ≤ 5.5V and V _{CCA} ≤ V _{CCB} .		
2	A1	I/O	Input/output A1. Reference to Vcca.		
3	A2	I/O	Input/output A2. Reference to V _{CCA} .		
4	A3	I/O	Input/output A3. Reference to V _{CCA} .		
5	A4	I/O	Input/output A4. Reference to V _{CCA} .		
6	NC	_	No internal connection.		
7	GND	_	Ground.		
8	OE	I	Output Enable (Active High). Pull OE low to place all outputs in 3-state mode. Referenced to V _{CCA} .		
9	NC	_	No internal connection.		
10	B4	I/O	Input/output B4. Reference to V _{CCB} .		
11	В3	I/O	Input/output B3. Reference to V _{CCB} .		
12	B2	I/O	Input/output B2. Reference to V _{CCB} .		
13	B1	I/O	Input/output B1. Reference to V _{CCB} .		
14	Vccв	Р	B Ports Supply Voltage.2.3V ≤ V _{CCB} ≤ 5.5V.		
_	Thermal Pad	_	Exposed pad should be soldered to PCB board and connected to GND or left floating.		

⁽¹⁾ I=input, O=output, I/O=input and output, P=power

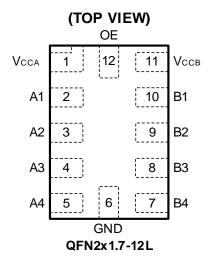




PIN	NAME	TYPE (1)	FUNCTION			
QFN2x2-12L	NAME	TIPE	FONCTION			
1	A1	I/O	Input/output A1. Reference to V _{CCA} .			
2	A2	I/O	Input/output A2. Reference to V _{CCA} .			
3	A3	I/O	Input/output A3. Reference to V _{CCA} .			
4	A4	I/O	Input/output A4. Reference to Vcca.			
5	GND	_	Ground.			
6	OE	I	Output Enable (Active High). Pull OE low to place all outputs in 3-state mode. Referenced to Vcca.			
7	B4	I/O	Input/output B4. Reference to V _{CCB} .			
8	В3	I/O	Input/output B3. Reference to V _{CCB} .			
9	B2	I/O	Input/output B2. Reference to V _{CCB} .			
10	B1	I/O	Input/output B1. Reference to V _{CCB} .			
11	V _{CCB}	Р	B Ports Supply Voltage.2.3V ≤ V _{CCB} ≤ 5.5V.			
12	Vcca	Р	A Port Supply Voltage.1.65V ≤ V _{CCA} ≤ 5.5V and V _{CCA} ≤ V _{CCB} .			
Exposed Pad	GND	-	Exposed pad should be soldered to PCB board and connected to GND or left floating.			

⁽²⁾ I=input, O=output, I/O=input and output, P=power

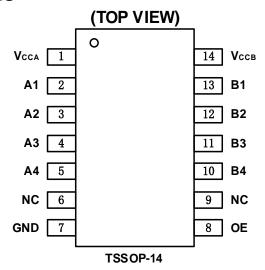




11. D = 001(11. 1101)					
PIN	NAME	TYPE (1)	FUNCTION		
QFN2x1.7-12L	NAME	I I PE (7	FUNCTION		
1	V _{CCA}	Р	A Port Supply Voltage.1.65V ≤ V _{CCA} ≤5.5V and V _{CCA} ≤ V _{CCB} .		
2	A1	I/O	Input/output A1. Reference to V _{CCA} .		
3	A2	I/O	Input/output A2. Reference to Vcca.		
4	A3	I/O	Input/output A3. Reference to Vcca.		
5	A4	I/O	Input/output A4. Reference to V _{CCA} .		
6	GND	_	Ground.		
7	B4	I/O	Input/output B4. Reference to Vccb.		
8	В3	I/O	Input/output B3. Reference to V _{CCB} .		
9	B2	I/O	Input/output B2. Reference to Vccb.		
10	B1	I/O	Input/output B1. Reference to Vccb.		
11	V _{CCB}	Р	B Ports Supply Voltage.2.3V ≤ V _{CCB} ≤ 5.5V.		
12	OE	I	Output Enable (Active High). Pull OE low to place all outputs in 3-state mode. Referenced to V _{CCA} .		

⁽¹⁾ I=input, O=output, I/O=input and output, P=power





PIN	NAME	TYPE (1)	FUNCTION
TSSOP-14	NAME	ITPE ("	FUNCTION
1	V _{CCA}	Р	A Port Supply Voltage.1.65V ≤ V _{CCA} ≤ 5.5V and V _{CCA} ≤ V _{CCB}
2	A1	I/O	Input/output A1. Reference to V _{CCA} .
3	A2	I/O	Input/output A2. Reference to V _{CCA} .
4	A3	I/O	Input/output A3. Reference to V _{CCA} .
5	A4	I/O	Input/output A4. Reference to V _{CCA} .
6	NC	-	No internal connection.
7	GND	_	Ground.
8	OE	I	Output Enable (Active High). Pull OE low to place all outputs in 3-state mode. Referenced to V _{CCA} .
9	NC	-	No internal connection.
10	B4	I/O	Input/output B4. Reference to V _{CCB} .
11	В3	I/O	Input/output B3. Reference to V _{CCB} .
12	B2	I/O	Input/output B2. Reference to V _{CCB} .
13	B1	I/O	Input/output B1. Reference to V _{CCB} .
14	V _{CCB}	Р	B Ports Supply Voltage.2.3V ≤ V _{CCB} ≤ 5.5V.

⁽²⁾ I=input, O=output, I/O=input and output, P=power



SPECIFICATIONS

Absolute Maximum Ratings

Over operating free-air temperature range (unless otherwise noted) (1)

SYMBOL	PARAMETER		MIN	MAX	UNIT
V _{CCA}	Supply Voltage Range	-0.3	6.0	V	
Vccв	Supply Voltage Range	-0.3	6.0	V	
		A port	-0.3	6.0	
V _I ⁽²⁾	Input Voltage Range	B port	-0.3	6.0	V
		OE	-0.3	6.0	V
Vo ⁽²⁾	Voltage range applied to any output in the high-	A port	-0.3	6.0	V
VO(-)	impedance or power-off state	B port	-0.3	6.0	V
Vo ⁽²⁾⁽³⁾	Voltage range applied to any output in the high or	A port	-0.3	Vcca+0.3	V
VOCAC	low state	B port	-0.3	V _{CCB} +0.3	V
lıĸ	Input clamp current	V _I <0		-50	mA
Іок	Output clamp current	Vo<0		-25	mA
lo	Continuous output current			±50	mA
	Continuous current through VCCA, VCCB or GND		±100	mA	
TJ	Junction Temperature			150	°C
T _{stg}	Storage temperature		-65	+150	

⁽¹⁾ Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

ESD Ratings

			VALUE	UNIT
Vison	V _(ESD) Electrostatic discharge	Human-body model (HBM)	±5000	V
V (ESD)		Machine Model (MM)	±400	V

⁽²⁾ The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

⁽³⁾ The value of V_{CCA} and V_{CCB} are provided in the recommended operating conditions table.



Recommended Operating Conditions

 V_{CCI} is the supply voltage associated with the input port. V_{CCO} is the supply voltage associated with the output port.

PARAMETER		CONDITIONS	MIN	TYP	MAX	UNIT
Supply voltage (1)	Vcca		1.65		5.5	V
Supply voltage (*)	V _{CCB}		2.3		5.5	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \
	A port I/Os	V _{CCA} = 1.65 V to 1.95 V V _{CCB} = 2.3 V to 5.5 V	Vccı - 0.2		Vccı	V
High-level input voltage	A-port I/Os	V _{CCA} = 2.3 V to 5.5 V V _{CCB} = 2.3 V to 5.5 V	Vccı - 0.4		Vccı	V
(V _{IH})	B-port I/Os	V _{CCA} = 1.65 V to 5.5 V V _{CCB} = 2.3 V to 5.5 V	V _{CCI} - 0.4		V _{CCI}	V
	OE input	V _{CCA} = 1.65 V to 5.5 V V _{CCB} = 2.3 V to 5.5 V	V _{CCA} × 0.8		5.5	V
	A-port I/Os	V _{CCA} = 1.65 V to 5.5 V V _{CCB} = 2.3 V to 5.5 V	0		0.15	V
Low-level input voltage (V _{IL})	B-port I/Os	$V_{CCA} = 1.65 \text{ V to } 5.5 \text{ V}$ $V_{CCB} = 2.3 \text{ V to } 5.5 \text{ V}$	0		0.15	V
. ,	OE input	V _{CCA} = 1.65 V to 5.5 V V _{CCB} = 2.3 V to 5.5 V	0		V _{CCA} × 0.25	V
		A-port I/Os push-pull driving			10	ns/V
Input transition rise or fall rate($\Delta t/\Delta v$)		B-port I/Os push-pull driving			10	ns/V
		Control input			10	ns/V
T _A Operating free-air temp	perature		-40		85	°C

⁽¹⁾ V_{CCA} must be less than or equal to V_{CCB}.
(2) The maximum V_{IL} value is provided to ensure that a valid V_{OL} is maintained. The V_{OL} value is V_{IL} plus the voltage drop across the pass gate transistor.



PACKAGE/ORDERING INFORMATION

PRODUCT	ORDERING NUMBER	TEMPERATURE RANGE	PACKAGE LEAD	PACKAGE MARKING (1)	MSL ⁽²⁾	PACKAGE OPTION
	RS0104YTQF14	-40°C ~+85°C	QFN3.5x3.5- 14L	RS0104	MSL3	Tape and Reel,5000
RS0104	RS0104YTQE12	-40°C ~+85°C	QFN2x2-12L	0104	MSL3	Tape and Reel,3000
	RS0104YUTQH12	-40°C ~+85°C	QFN2x1.7-12L	0104	MSL3	Tape and Reel,4000
	RS0104YQ	-40°C ~+85°C	TSSOP-14	RS0104	MSL3	Tape and Reel,4000

NOTE:

⁽¹⁾ There may be additional marking, which relates to the lot trace code information(data code and vendor code), the logo or the environmental category on the device.

⁽²⁾ MSL, The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications.



Electrical Characteristics

PA	ARAMETER	CONDITIONS	Vcca	V _{ССВ}	TEMP	MIN	TYP	MAX	UNITS	
Vона	Port A output high voltage	$I_{OH} = -20 \mu A$ $V_{IB} \ge V_{CCB} - 0.4V$	1.65V to 5.5V	2.3V to 5.5V	Full	V _{CCA} × 0.7		5.5		
Vola	Port A output low voltage	$I_{OL} = 1mA$ $V_{IB} \le 0.15 \text{ V}$	1.65V to 5.5V	2.3V to 5.5V	Full			0.3	V	
V _{ОНВ}	Port B output high voltage	I _{OH} = −20 μA V _{IA} ≥ V _{CCA} − 0.4 V	1.65V to 5.5V	2.3V to 5.5V	Full	V _{ССВ} × 0.7			V	
V _{OLB}	Port B output low voltage	$I_{OL} = 1mA$ $V_{IA} \leq 0.15 \text{ V}$	1.65V to 5.5V	2.3V to 5.5V	Full			0.3		
lı	Input leakage	OE	1.65V to 5.5V	2.3V to 5.5V	+25° C			±1	μA	
11	current	OL	1.03 0 10 3.3 0	2.3 10 3.3 1	Full			±1.5	μΛ	
		A Ports	0V	0V to 5.5V	+25° C			±0.5	μA	
1	Partial power	A Ports	OV.	0 0 10 5.5 0	Full			±1	μΑ	
l _{off}	down current	D. Dorto	0)/ to F F)/	0V	+25° C			±0.5		
		B Ports 0V to 5.5V		UV	Full			±1	μA	
	High- impedance	A or B port		+25° C			±0.5			
l _{OZ}	State output current	OE=0V		2.3V to 5.5V	Full			±1	μΑ	
			1.65V to V _{CCB}	2.3V to 5.5V	Full			1.0		
I _{CCA}	V _{CCA} supply current	$V_1 = V_0 = open$ $I_0 = 0$	$V_1 = V_0 = open$ $I_0 = 0$	5.5V	0V	Full			1.0	μA
			0V	5.5V	Full			-1	F	
			1.65V to V _{CCB}	2.3V to 5.5V	Full			10		
I _{CCB}	V _{CCB} supply current	$V_1 = V_0 = open$ $I_0 = 0$	5.5V	0V	Full			-1	μΑ	
			0V	5.5V	Full			1		
Icca + Iccb	Combined supply current	V _I = V _{CCI} or GND I _O = 0	1.65V to V _{CCB}	2.3V to 5.5V	Full			15	μΑ	
Iccza	V _{CCA} supply current	V _I = V _{CCI} or 0V I _O = 0, OE=0V	1.65V to V _{CCB}	2.3V to 5.5V	Full			1	μΑ	
I _{CCZB}	V _{CCB} supply current	$V_I = V_{CCI}$ or $0V$ $I_O = 0$, $OE=0V$	2.3V to 5.5V	2.3V to 5.5V	Full			1	μΑ	
Сі	Input capacitance	OE	3.3V	3.3V	+25° C		2.5		pF	
	Input-to- output	A port	3.3V	3.3V	+25° C		5		_	
Cio	internal capacitance	B port	3.3V	3.3V	+25° C		5		pF	

⁽¹⁾ V_{CCI} is the V_{CC} associated with the input port.
(2) V_{CCO} is the V_{CC} associated with the output port
(3) V_{CCA} must be less than or equal to V_{CCB}.



Timing Requirements

V_{CCA}=1.8V±0.15 V

		V _{CCB} =2.5V ±0.2V	V _{CCB} =3.3V ±0.2V	V _{CCB} =5V ±0.2V	UNIT	
		TYP	TYP	TYP	UNIT	
Data rate	Push-pull driving	21	22	24	Mhaa	
	Open-drain driving	2	2	2	Mbps	
Pulse duration(t _w)	Push-pull driving (data inputs)	47	45	41		
	Open-drain driving (data inputs)	500	500	500	ns	

V_{CCA}=2.5V±0.15 V

		V _{CCB} =2.5V ±0.2V	V _{CCB} =3.3V ±0.2V	V _{CCB} =5V ±0.2V	LINIT	
		TYP	TYP	TYP	UNIT	
5	Push-pull driving	20	22	24	Mhaa	
Data rate	Open-drain driving	2	2	2	Mbps	
Pulse duration(t _w)	Push-pull driving (data inputs)	50	45	41	20	
	Open-drain driving (data inputs)	500	500	500	ns	

Vcca=3.3V±0.15 V

* CCA-OIO	7 _0110 V			
		V _{CCB} =3.3V ±0.2V	V _{CCB} =5V ±0.2V	LINIT
		TYP	TYP	UNIT
Data rata	Push-pull driving	23	24	Mhna
Data rate	Open-drain driving	2	2	Mbps
Pulse	Push-pull driving (data inputs)	43	41	no
duration(tw)	Open-drain driving (data inputs)	500	500	ns

$V_{CCA}=5V\pm0.15 V$

V CCA-O V	-0.10 4		
		V _{CCB} =5V ±0.2V	UNIT
		ТҮР	UNIT
Data rata	Push-pull driving	24	Mhna
Data rate	Open-drain driving	2	Mbps
Pulse	Push-pull driving (data inputs)	41	no
duration(tw)	Open-drain driving (data inputs)	500	ns



Switching Characteristics: V_{CCA}=1.8V ± 0.15V

PARAMETER		CONDITIONS		V _{CCB} =2.5V±0.2V	V _{CCB} =3.3V±0.2V	V _{CCB} =5V±0.2V	LIMITO	
PA	RAMETER	CONDITIONS		TYP	TYP	TYP	UNITS	
	Propagation		Push-pull driving	2.5	3.1	4.5		
t _{PHL}	delay time high-to-low output	A-to-B	Open-drain driving	26.1	26.4	26.6	ns	
	Propagation		Push-pull driving	4.2	3.7	3.6		
tplh	delay time low-to-high output	A-to-B	Open-drain driving	221	183	143	ns	
	Propagation		Push-pull driving	2.1	2.0	2.2		
t _{PHL}	delay time high-to-low output	B-to-A	Open-drain driving	26.1	26.1	26.2	ns	
	Propagation		Push-pull driving	1.8	1.6	1.5		
tplh	delay time low-to-high output	B-to-A	Open-drain driving	173	89	66	ns	
ten	Enable time	OE-to-A or B		25	21	19	ns	
t _{dis}	Disable time	OE-to-A	or B	1250	1250	1250	ns	
٠.	Input rise	A port rise	Push-pull driving	6.9	6.1	5.6	no	
t _{rA}	time	time	Open-drain driving	118	39	13	ns	
	Input rise	B port	Push-pull driving	5.8	4.8	4.1		
t _{rB}	time	rise time	Open-drain driving	166	127	75	ns	
	Input fall	A port	Push-pull driving	3.0	2.8	2.7		
t fA	time	fall time	Open-drain driving	1.9	1.7	1.6	ns	
4	Input fall	B port	Push-pull driving	4.8	6.2	8.4	20	
t fB	time fall ti		Open-drain driving	2.3	2.4	2.8	ns	
tsk(O)	Skew(time), output	Channel-to-Channel Skew		0.5	0.5	0.5	ns	
Mavim	num data rate	Push-pul	driving	21	22	24	Mhne	
ινιαλίΙΙ	ium uata rate	Open-dra	in driving	2	2	2	Mbps	



Switching Characteristics: V_{CCA}=2.5V ± 0.15V

PARAMETER		CONDITIONS		V _{CCB} =2.5V±0.2V	V _{CCB} =3.3V±0.2V	V _{CCB} =5V±0.2V	LINUTC	
PA	KAMETEK	CONDITIONS		TYP	TYP	TYP	UNITS	
tphL	Propagation delay time	A-to-B	Push-pull driving	2.8	3.4	5.0	ns	
VPHL	high-to-low output	77 10 15	Open-drain driving	26.3	26.5	26.6	113	
t plh	Propagation delay time	A-to-B	Push-pull driving	2.7	2.5	2.4	ns	
IPLH	low-to-high output	A-10-D	Open-drain driving	198	169	131	113	
t	Propagation delay time	B-to-A	Push-pull driving	2.5	2.4	2.5	ns	
t _{PHL}	high-to-low output	D-10-A	Open-drain driving	26.4	26.5	26.6	115	
tou	Propagation delay time	B-to-A	Push-pull driving	2.1	2.0	1.9	ns	
tplh	low-to-high output	D-10-74	Open-drain driving	196	138	63	115	
t _{en}	Enable time	OE-to-A or B		24	20	17	ns	
t _{dis}	Disable time	OE-to-A or B		1250	1250	1250	ns	
	Input rise	A port	Push-pull driving	3.4	2.9	2.7		
t _{rA}	time	rise time	Open-drain driving	156	92	13	ns	
	Input rise	B port	Push-pull driving	4.7	3.5	2.7		
t rB	time	rise time	Open-drain driving	160	124	81	ns	
	Input fall	A port	Push-pull driving	5.1	5.2	5.0		
t fA	time	fall time	Open-drain driving	2.1	2.0	1.8	ns	
4	Input fall	B port	Push-pull driving	5.0	6.4	8.7	20	
t fB	time	fall time	Open-drain driving	2.0	2.2	2.8	ns	
tsk(O)	Skew(time), output	Channel-to-channel skew		0.5	0.5	0.5	ns	
Maxim	num data rate	Push-pul	driving	20	22	24	Mbps	
ividXiII	iuiii uala lale	Open-drain driving		2	2	2	INIDAS	



Switching Characteristics: $V_{CCA}=3.3V \pm 0.3V$

PARAMETER		CONDITIONS		V _{CCB} =3.3V±0.2V	V _{CCB} =5V±0.2V	LINUTO	
Ρ/	AKAMETEK	'	CONDITIONS	TYP	ТҮР	UNITS	
tphL	Propagation delay time	A-to-B	Push-pull driving	3.6	5.1	ns	
CFIIL	high-to-low output	7.10 5	Open-drain driving	26.4	26.6	110	
t _{PLH}	Propagation delay time	A-to-B	Push-pull driving	2.3	2.1	ns	
(PLH	low-to-high output	A-10-D	Open-drain driving	155	109	113	
t _{PHL}	Propagation delay time	B-to-A	Push-pull driving	3.1	3.3	ns	
PHL	high-to-low output	D-10-A	Open-drain driving	26.5	26.7	113	
4	Propagation delay time	delay time ow-to-high B-to-A	Push-pull driving	1.9	1.8	20	
IPLH	low-to-high output		Open-drain driving	158	87	ns	
t _{en}	Enable time	OE-to-A or B		19	15	ns	
t _{dis}	Disable time	OE-to-A or B		1250	1250	ns	
4 .	Input rice time	A port rise	Push-pull driving	2.3	2.1	no	
t_{rA}	Input rise time	time	Open-drain driving	117	48	ns	
4 -	Input rice time	B port rise	Push-pull driving	3.0	2.4	20	
t rB	Input rise time	time	Open-drain driving	117	75	ns	
4	Input fall time	A port fall	Push-pull driving	8.0	7.6	no	
t_fA	input iaii tiine	time	Open-drain driving	2.2	2.1	ns	
4	Input fall time	B port fall	Push-pull driving	8.2	10.8	20	
t _{fB}	Input fall time time		Open-drain driving	2.1	2.4	ns	
tsk(O)	Skew(time), output	Channel-to-channel skew		0.5	0.5	ns	
Maxim	um data rate	Push-pull driv	ing	23	24	Mhna	
iviaXIIII	uiii uala fale	Open-drain driving		2	2	Mbps	

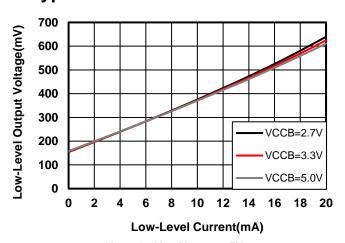


Switching Characteristics: V_{CCA}=5.0V ± 0.35V

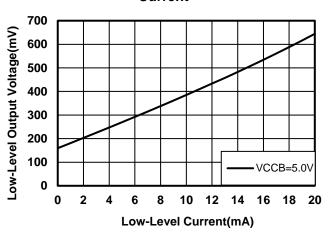
PARAMETER		CONDITIONS		V _{CCB} =5V±0.2V	UNITS
•	AKAMETEK		CNDITIONS	TYP	UNITS
t _{PHL}	Propagation delay time	A-to-B	Push-pull driving	5.6	ns
41 TIE	high-to-low output	/	Open-drain driving	26.8	
tpLH	Propagation delay time	A-to-B	Push-pull driving	2.0	ns
IPLH	low-to-high output	A-10-D	Open-drain driving	155	113
t _{PHL}	Propagation delay time	B-to-A	Push-pull driving	5.8	ns
PHL	high-to-low output	B-10-A	Open-drain driving	27.5	113
t pLH	Propagation delay time	B-to-A	Push-pull driving	1.8	ns
IPLH	low-to-high output	B-10-A	Open-drain driving	160	113
t _{en}	Enable time	OE-to-A or B		17	ns
t _{dis}	Disable time	OE-to-A or B		1250	ns
4.	Input rice time	A port rise time	Push-pull driving	1.9	20
t_{rA}	Input rise time	A port rise time	Open-drain driving	105	ns
4 -	Input rice time	D part rice time	Push-pull driving	2.3	20
t rB	Input rise time	B port rise time	Open-drain driving	95	ns
4	Input fall time	A port fall time	Push-pull driving	9.0	no
t _{fA}	input iaii tiinie	A port rail time	Open-drain driving	2.6	- ns
t _{fB}	Input fall time	B port fall time	Push-pull driving	8.9	no
เเห	input iaii tiine	b port rail time	Open-drain driving	2.5	ns
tsk(O)	Skew(time), output	Channel-to-chan	nel skew	0.5	ns
Maximum data rata		Push-pull driving		24	Mbps
Maximum data rate		Open-drain driving		2	ivibps



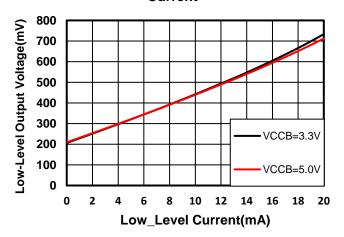
Typical Characteristics



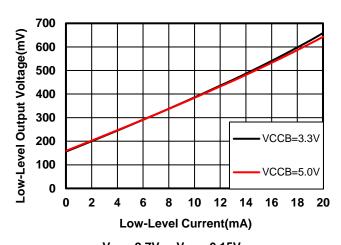
V_{CCA}=1.8V V_{IL(A)}=0.15V Figure1: Low-Level Output Voltage vs Low-Level Current



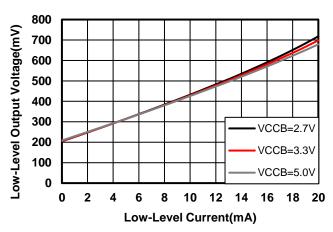
V_{CCA}=3.3V V_{IL(A)}=0.15V Figure3: Low-Level Output Voltage vs Low-Level Current



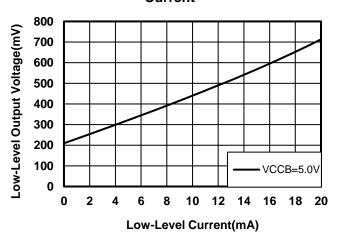
V_{CCA}=2.7V V_{IL(A)}=0.20V Figure5: Low-Level Output Voltage vs Low-Level Current



V_{CCA}=2.7V V_{IL(A)}=0.15V Figure2: Low-Level Output Voltage vs Low-Level Current



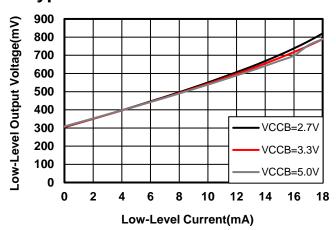
V_{CCA}=1.8V V_{IL(A)}=0.20V Figure4: Low-Level Output Voltage vs Low-Level Current



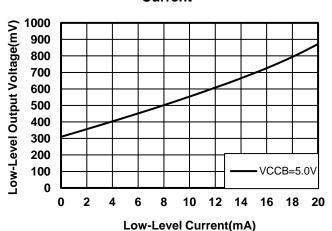
V_{CCA}=3.3V V_{IL(A)}=0.20V Figure6: Low-Level Output Voltage vs Low-Level Current



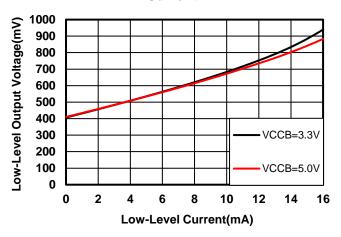
Typical Characteristics



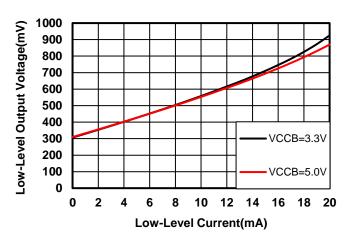
V_{CCA}=1.8V V_{IL(A)}=0.30V Figure7: Low-Level Output Voltage vs Low-Level Current



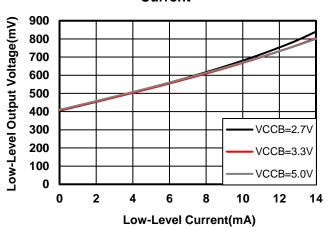
V_{CCA}=3.3V V_{IL(A)}=0.30V Figure9: Low-Level Output Voltage vs Low-Level Current



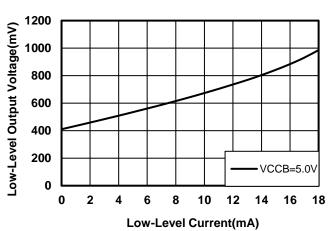
V_{CCA}=2.7V V_{IL(A)}=0.40V Figure11: Low-Level Output Voltage vs Low-Level Current



V_{CCA}=2.7V V_{IL(A)}=0.30V Figure8: Low-Level Output Voltage vs Low-Level Current



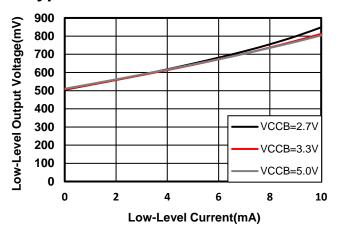
V_{CCA}=1.8V V_{IL(A)}=0.40V Figure10: Low-Level Output Voltage vs Low-Level Current



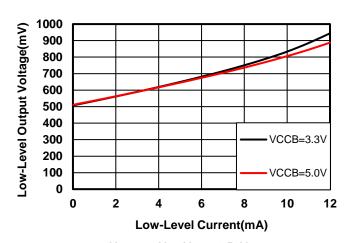
V_{CCA}=3.3V V_{IL(A)}=0.40V Figure12: Low-Level Output Voltage vs Low-Level Current



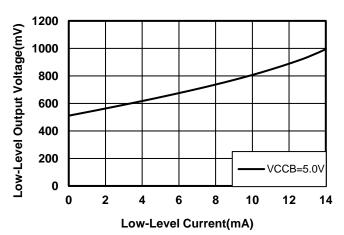
Typical Characteristics



V_{CCA}=1.8V V_{IL(A)}=0.50V Figure13: Low-Level Output Voltage vs Low-Level Current



V_{CCA}=2.7V V_{IL(A)}=0.50V Figure14: Low-Level Output Voltage vs Low-Level Current



V_{CCA}=3.3V V_{IL(A)}=0.50V Figure15: Low-level Output Voltage vs Low-Level Current



Parameter Measurement Information

Unless otherwise noted, all input pulses are supplied by generators having the following characteristics:

- PRR 10 MHz
- $Zo = 50 \Omega$
- $dv/dt \ge 1 V/ns$

Note: All input pulses are measured one at a time, with one transition per measurement.

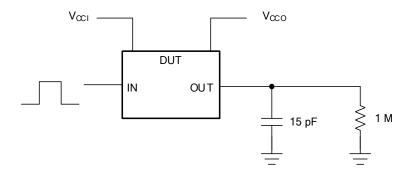


Figure 16. Data Rate, Pulse Duration, Propagation Delay, Output Rise And Fall Time Measurement Using A Push-Pull Driver

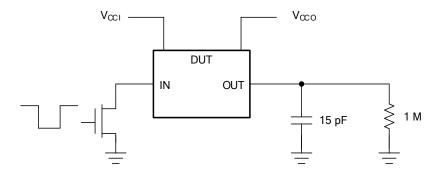


Figure 17. Data Rate, Pulse Duration, Propagation Delay, Output Rise And Fall Time Measurement Using an Open-Drain Driver

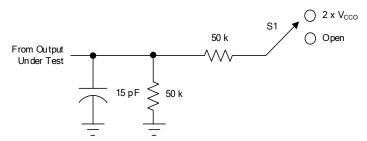


Figure 18. Load Circuit for Enable/Disable Time Measurement

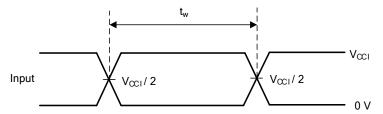
Table 1. Switch Configuration for Enable/Disable Timing

TEST	S1
t _{PZL} ⁽¹⁾ , t _{PLZ} ⁽²⁾	2 × V _{CCO}
t _{PHZL} ⁽¹⁾ , t _{PZH} ⁽²⁾	Open

⁽¹⁾ t_{PZL} and t_{PZH} are the same as t_{en} .

⁽²⁾ t_{PLZ} and t_{PHZ} are the same as t_{dis} .





(1) All input pulses are measured one at a time, with one transition per measurement.

Figure 19. Voltage Waveforms Pulse Duration

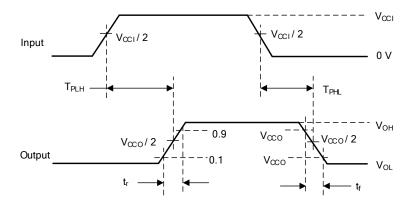


Figure 20. Voltage Waveforms Propagation Delay Times

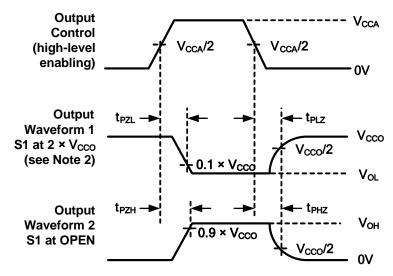


Figure 21. Voltage Waveforms Enable and Disable



Feature Description

Overview

The RS0104 device is a directionless voltage-level translator specifically designed for translating logic voltage levels. The A port is able to accept I/O voltages ranging from 1.65 V to 5.5 V, while the B port can accept I/O voltages from 2.3 V to 5.5 V. The device is a pass-gate architecture with edge-rate accelerators (one-shots) to improve the overall data rate. 10-k Ω pullup resistors, commonly used in open-drain applications, have been conveniently integrated so that an external resistor is not needed. While this device is designed for open-drain applications, the device can also translate push-pull CMOS logic outputs.

Architecture

The RS0104 architecture (see Figure 22) is an auto-direction-sensing based translator that does not require a direction-control signal to control the direction of data flow from A to B or from B to A. These two bidirectional channels independently determine the direction of data flow without a direction-control signal. Each I/O pin can be automatically reconfigured as either an input or an output, which is how this auto-direction feature is realized.

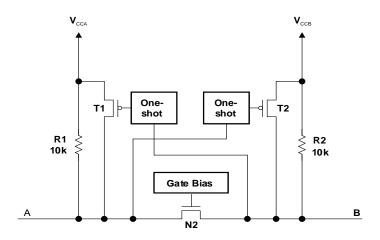


Figure 22. Architecture of a RS0104 Cell

The RS0104 employs two key circuits to enable this voltage translation:

- 1) An N-channel pass-gate transistor topology that ties the A-port to the B-port
- 2) Output one-shot (O.S.) edge-rate accelerator circuitry to detect and accelerate rising edges on the A or B Ports.

Input Driver Requirements

The continuous dc-current "sinking" capability is determined by the external system-level open-drain (or push-pull) drivers that are interfaced to the RS0104 I/O pins. Since the high bandwidth of these bidirectional I/O circuits is used to facilitate this fast change from an input to an output and an output to an input, they have a modest dc-current "sourcing" capability of hundreds of micro-Amps, as determined by the internal $10-k\Omega$ pullup resistors.

The fall time (t_{fA} , t_{fB}) of a signal depends on the edge-rate and output impedance of the external device driving RS0104 data I/Os, as well as the capacitive loading on the data lines.

Similarly, the t_{PHL} and max data rates also depend on the output impedance of the external driver. The values for t_{fA} , t_{fB} , t_{PHL} and maximum data rates in the data sheet assume that the output impedance of the external driver is less than 50 Ω .



Feature Description

Output Load Considerations

We recommend careful PCB layout practices with short PCB trace lengths to avoid excessive capacitive loading and to ensure that proper O.S. triggering takes place. PCB signal trace-lengths should be kept short enough such that the round-trip delay of any reflection is less than the one-shot duration. This improves signal integrity by ensuring that any reflection sees a low impedance at the driver. The O.S. circuits have been designed to stay on for approximately 30 ns. The maximum capacitance of the lumped load that can be driven also depends directly on the one-shot duration. With very heavy capacitive loads, the one-shot can time-out before the signal is driven fully to the positive rail. The O.S. duration has been set to best optimize trade-offs between dynamic ICC, load driving capability, and maximum bit-rate considerations. Both PCB trace length and connectors add to the capacitance that the RS0104 device output sees, so it is recommended that this lumped-load capacitance be considered to avoid O.S. retriggering, bus contention, output signal oscillations, or other adverse system-level affects.

Enable and Disable

The RS0104 device has an OE input that is used to disable the device by setting OE low, which places all I/Os in the Hi-Z state. The disable time (t_{dis}) indicates the delay between the time when OE goes low and when the outputs are disabled (Hi-Z). The enable time (t_{en}) indicates the amount of time the user must allow for the one-shot circuitry to become operational after OE is taken high.

Pullup or Pulldown Resistors on I/O Lines

Each A-port I/O has an internal $10-k\Omega$ pullup resistor to V_{CCA} , and each B-port I/O has an internal $10-k\Omega$ pullup resistor to V_{CCB} . If a smaller value of pullup resistor is required, an external resistor must be added from the I/O to V_{CCA} or V_{CCB} (in parallel with the internal $10-k\Omega$ resistors). Adding lower value pull-up resistors will affect V_{OL} levels, however. The internal pull-ups of the RS0104 are disabled when the OE pin is low.



Application Information

The RS0104 device can be used to bridge the digital-switching compatibility gap between two voltage nodes to successfully interface logic threshold levels found in electronic systems. It should be used in a point-to-point topology for interfacing devices or systems operating at different interface voltages with one another. Its primary target application use is for interfacing with open-drain drivers on the data I/Os such as I₂C or 1-wire, where the data is bidirectional and no control signal is available. The device can also be used in applications where a push-pull driver is connected to the data I/Os, but the RS0104 might be a better option for such push-pull applications.

Typical Application

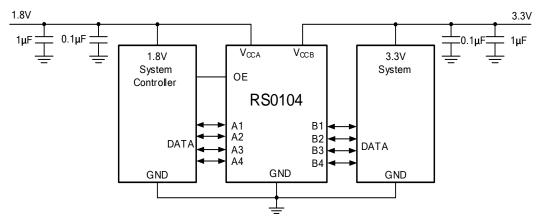
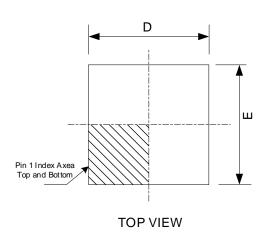
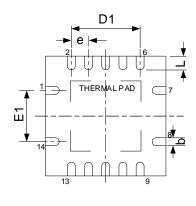


Figure 23. Typical Application Circuit

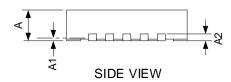


PACKAGE OUTLINE DIMENSIONS QFN3.5x3.5-14L





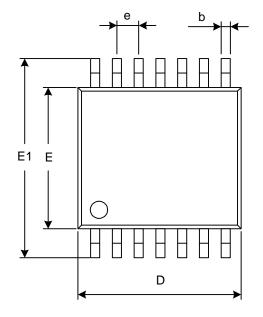
BOTTOM VIEW

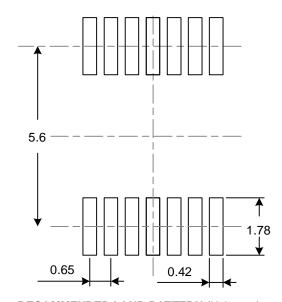


Cumbal	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min	Max	Min	Max	
A	0.800	1.000	0.031	0.039	
A1	0.000	0.050	0.000	0.002	
A2	0.200	0.200 REF 0.008 REF			
b	0.180	0.300	0.007	0.012	
D	3.350	3.650	0.132	0.144	
D1	2.000) TYP	0.079 TYP		
E	3.350	3.650	0.007	0.012	
E1	1.500) TYP	0.059 TYP		
е	0.500) TYP	0.020 TYP		
L	0.300	0.500	0.012	0.020	



TSSOP-14





RECOMMENDED LAND PATTERN (Unit: mm)

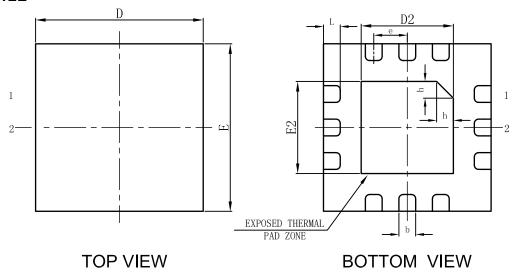


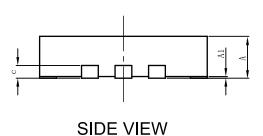


Comple of	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min	Max	Min	Max	
А		1.200		0.047	
A1	0.050	0.150	0.002	0.006	
A2	0.800	1.050	0.031	0.041	
b	0.190	0.300	0.007	0.012	
С	0.090	0.200	0.004	0.008	
D	4.860	5.100	0.191	0.201	
E	4.300	4.500	0.169	0.177	
E1	6.250	6.550	0.246	0.258	
е	0.650	(BSC)	0.026	(BSC)	
L	0.500	0.700	0.700 0.020		
Н	0.250	(TYP)	0.010)(TYP)	
θ	1°	7°	1°	7°	



QFN2x2-12L

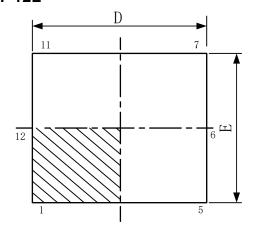


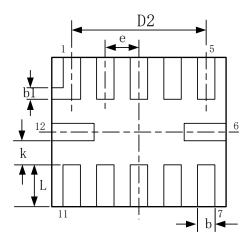


Complete	Dimensions I	In Millimeters	Dimensions In Inches		
Symbol	Min	Min Max		Max	
А	0.450	0.550	0.018	0.022	
A1	0.000	0.050	0.000	0.002	
С	0.100	0.200	0.004	0.008	
b	0.150	0.250	0.006	0.010	
D	1.900	2.100	0.075	0.083	
E	1.900	2.100	0.075	0.083	
D2	1.000	1.200	0.039	0.057	
E2	1.000	1.200	0.039	0.057	
е	0.400	BSC	0.016	BSC	
h	0.150	0.250	0.006	0.010	
L	0.150	0.250	0.006	0.010	



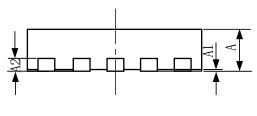
QFN2x1.7-12L





TOP VIEW

BOTTOM VIEW



SIDE VIEW

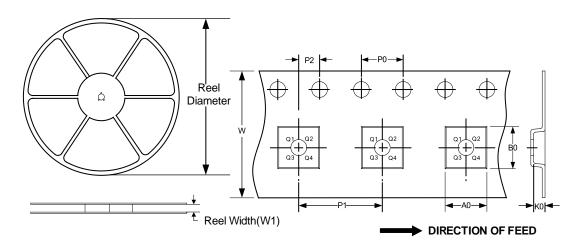
Cumbal	Dimensions	n Millimeters	Dimension	s In Inches	
Symbol	Min	Max	Min	Max	
A	0.450	0.550	0.018	0.022	
A1	0.000	0.050	0.000	0.002	
A2	0.152	0.152 REF 0.006 REF			
D	1.900	2.100	0.075	0.083	
E	1.600	1.800	0.063	0.071	
D2	1.500	1.700	0.059	0.067	
b	0.150	0.250	0.006	0.010	
b1	0.150	REF	0.006 REF		
k	0.250	REF	0.010 REF		
е	0.400	BSC	0.016 BSC		
L	0.400	0.600	0.016	0.024	



TAPE AND REEL INFORMATION

REEL DIMENSIONS

TAPE DIMENSION



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1(mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
QFN3.5x3.5-14L	13"	12.4	4.0	4.0	1.10	4.0	8.0	2.0	12.0	Q1
TSSOP-14	13"	12.4	6.95	5.60	1.20	4.0	8.0	2.0	12.0	Q1
QFN1.7x2-12L	7"	9.0	1.90	2.30	0.75	4.0	4.0	2.0	8.0	Q1
QFN2x2-12L	7"	9.0	2.13	2.13	0.88	4.0	4.0	2.0	8.0	Q1

单击下面可查看定价,库存,交付和生命周期等信息

>>润石